TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHCT125AF, TC74VHCT125AFN, TC74VHCT125AFT
TC74VHCT126AF, TC74VHCT126AFN, TC74VHCT126AFT

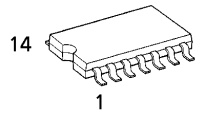
TC74VHCT125AF / AFN / AFT QUAD BUS BUFFER
TC74VHCT126AF / AFN / AFT QUAD BUS BUFFER

(Note) : The JEDEC SOP (FN) is not available in Japan.

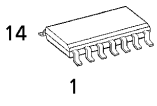
The TC74VHCT125A / 126A are high speed CMOS QUAD BUS BUFFERs fabricated with silicon gate C^2MOS technology.
They achieve the high speed operation similar to equivalent Bipolar Shottky TTL while maintaining the CMOS low power dissipation.
The TC74VHCT125A requires the 3-state control input $\overline{G}$ to be set high to place the output into the high impedance state, whereas the TC74VHCT126A requires the control input G to be set low to place the output into high impedance.
The input voltage are compatible with TTL output voltage.
This device may be used as a level converter for interfacing 3.3 V to 5 V system.
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output*1 pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input / output voltages such as battery back up, hot board insertion, etc.
*1: Vcc = 0 V

FEATURES :

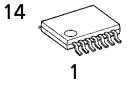
- High Speed ····· t_{pd} = 3.8 ns (typ.) at V_{CC} = 5 V
- Low Power Dissipation ····· I_{CC} = 4 μA (Max.) at Ta = 25°C
- Compatible with TTL outputs ···· V_{IL} = 0.8 V (Max.), V_{IH} = 2.0 V (Min.)
- Power Down Protection is provided on all inputs and outputs.
- Balanced Propagation Delays ····· $t_{pLH} \simeq t_{pHL}$
- Low Noise ····· V_{OLP} = 0.8 V (Max.)
- Pin and Function Compatible with the 74 series (74AC / HC / F / ALS / LS etc.) 125 / 126 type.



F (SOP14-P-300-1.27)
Weight : 0.18 g (Typ.)

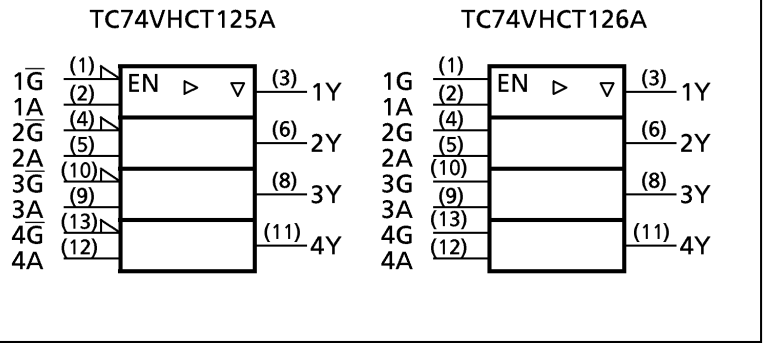


FN (SOL14-P-150-1.27)
Weight : 0.12 g (Typ.)

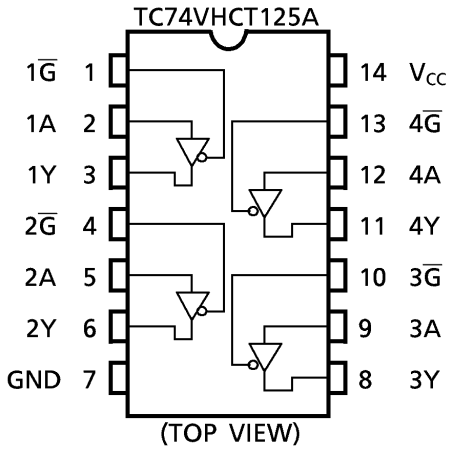


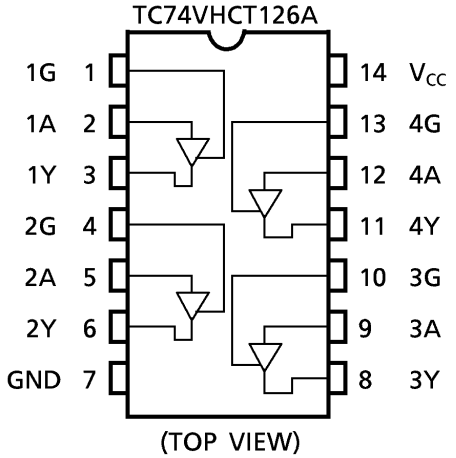
FT (TSSOP14-P-0044-0.65)
Weight : 0.06 g (Typ.)

IEC LOGIC SYMBOL



PIN ASSIGNMENT





980910EBA2

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TRUTH TABLE

TC74VHCT125A

INPUTS		OUTPUTS
$\overline{G}$	A	Y
H	X	Z
L	L	L
L	H	H

X : Don't Care
Z : High Impedance

TC74VHCT126A

INPUTS		OUTPUTS
G	A	Y
L	X	Z
H	L	L
H	H	H

X : Don't Care
Z : High Impedance

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7.0	V
DC Input Voltage	V_{IN}	−0.5~7.0	V
DC Output Voltage	V_{OUT}	−0.5~7.0 (Note 1)	V
		−0.5 ~ V_{CC} + 0.5 (Note 2)	
Input Diode Current	I_{IK}	−20	mA
Output Diode Current	I_{OK}	±20 (Note 3)	mA
DC Output Current	I_{OUT}	±25	mA
DC Vcc/Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	−65~150	°C

(Note 1) : Output in Off-State
(Note 2) : High or Low State. I_{OUT} absolute maximum rating must be observed.
(Note 3) : $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~5.5 (Note 4)	V
		0~V_{CC} (Note 5)	
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	dt / dV	0~20	ns / V

(Note 4) : Output in Off-State
(Note 5) : High or Low State

980910EBA2'

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- The information contained herein is subject to change without notice.

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITON		V_{CC} (V)	Ta = 25°C MIN.	Ta = 25°C TYP.	Ta = 25°C MAX.	Ta = −40~85°C MIN.	Ta = −40~85°C MAX.	UNIT
High - Level Input Voltage	V_{IH}			4.5~5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V_{IL}			4.5~5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	4.5	4.40	4.50	—	4.40	—	V
			I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	4.5	—	0.0	0.1	—	0.1	V
			I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input Leakage Current	I_{IN}	V_{IN} = 5.5 V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
3-State Output Off-state Current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		5.5	—	—	±0.25	—	±2.50	
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	
	I_{CCT}	PER INPUT : V_{IN} = 3.4 V OTHER INPUT : V_{CC} or GND		5.5	—	—	1.35	—	1.50	mA
Output Leakage Current	I_{OPD}	V_{OUT} = 5.5 V		0	—	—	0.5	—	5.0	μA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3$ ns)

PARAMETER	SYMBOL	TEST CONDITION			Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time	t_{pLH} t_{pHL}		5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5	ns
				50	—	5.3	7.5	1.0	8.5	
Output Enable Time	t_{pZL} t_{pZH}	RL = 1 kΩ	5.0 ± 0.5	15	—	3.6	5.1	1.0	6.0	
				50	—	5.1	7.1	1.0	8.0	
Output Disable Time	t_{pZL} t_{pZH}	RL = 1 kΩ	5.0 ± 0.5	50	—	6.1	8.8	1.0	10.0	
Output to Output Skew	t_{osLH} t_{osHL}	(Note 6)	5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input Capacitance	C_{IN}				—	4	10	—	10	pF
Output Capacitance	C_{OUT}				—	6	—	—	—	
Power Dissipation Capacitance (Note 7)	C_{PD}	TC74VHCT125A			—	14	—	—	—	
		TC74VHCT126A			—	15	—	—	—	

(Note 6) : Parameter guaranteed by design. $t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$

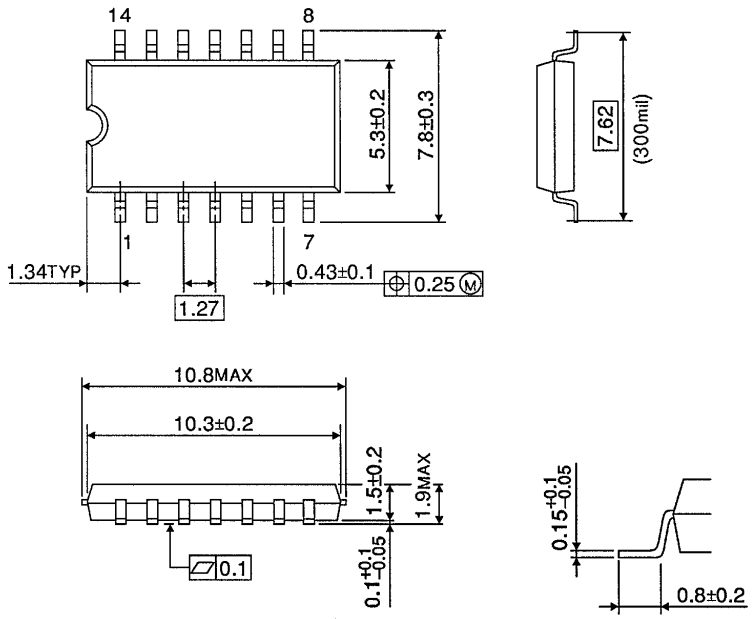
(Note 7) : C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per Gate)}$$

NOISE CHARACTERISTICS (Input $t_r = t_f = 3$ ns)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C		UNIT
			V_{CC} (V)	TYP.	LIMIT	
Quiet Output Maximum Dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	0.5	0.8	V
Quiet Output Minimum Dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−0.5	−0.8	V
Minimum High Level Dynamic Input Voltage	V_{IHD}	C_L = 50 pF	5.0	—	2.0	V
Maximum Low Level Dynamic Input Voltage	V_{ILD}	C_L = 50 pF	5.0	—	0.8	V

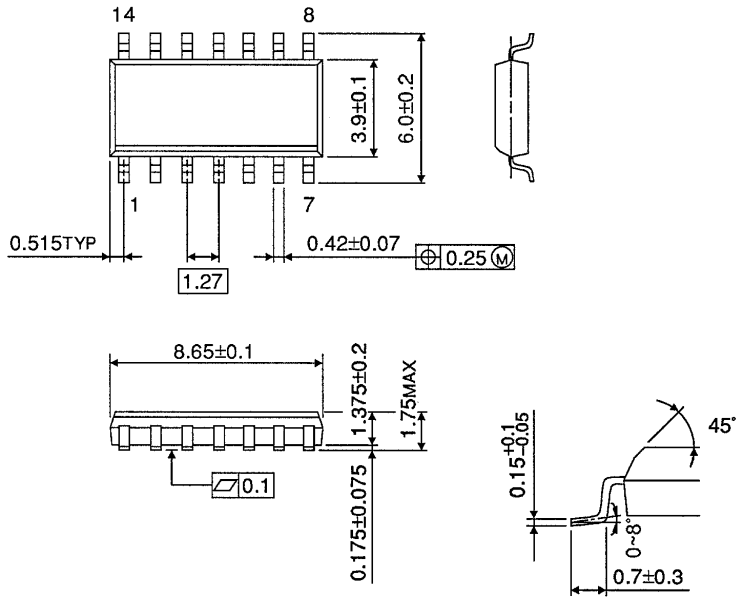
SOP 14 PIN (200 mil BODY) OUTLINE DRAWING (SOP14-P-300-1.27) Unit in mm



Weight : 0.18 g (Typ.)

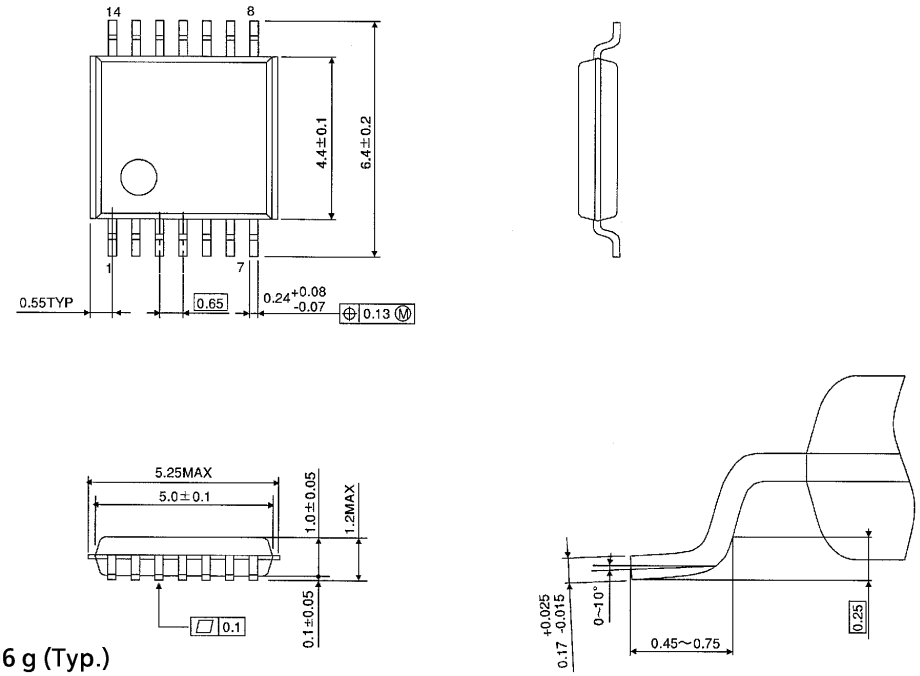
SOP 14 PIN (150 mil BODY) OUTLINE DRAWING (SOL14-P-150-1.27) Unit in mm

(Note) : This package is not available in Japan.



Weight : 0.12 g (Typ.)

TSSOP 14 PIN OUTLINE DRAWING (TSSOP14-P-0044-0.65) Unit in mm



Weight : 0.06 g (Typ.)

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2SC2712-Y,LF(T CEZ6V8,L3F DF3A5.6FU(TE85L,F) TLP2710(TP,E(T TLP385(GB-TPL,E(T DF2S6.8MFS,L3M(T SSM3J358R,LF(T TC7SH04FU,LJ(CT TDS4B212MX,ELF(S RN4985,LF(CT SSM6L36FE,LM(T TC7WZ08FK,LJ(CT TK100E10N1,S1X(S TPW3R70APL,L1Q(M TBC847B,LM(T TC7SZU04F,LJ(CT TK7R7P10PL,RQ(S2 TLP3412SRLA(TP,E(O 1SS361FV,L3F(T TC75S63TU,LF(T TC78H651FNG,EL TC7W08FU,LF(T TCKE805NA,RF(S TCR2LE36,LM(CT TLP2704(TP,E(T CES520,L3F(T TB6588FG,8,EL,JU TK7P60W,RVQ(S TLP4176G(TP,M,F) TC7S32F,LF(T